

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	546	vcsl and (dbr or mirror or reflector) with ("C" or Carbon or berrilium or "Be" or Zinc or Zn)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 13:42
L2	83	vcsl and (dbr or mirror or reflector) with ("C" or Carbon or berrilium or "Be" or Zinc or Zn) same AlGaAs	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 13:44
L3	46	vcsl and (dbr or mirror or reflector) with ("C" or Carbon or berrilium or "Be" or Zinc or Zn) same AlGaAs and (photodetector photodiode detector photo adj (detector diode))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 14:18
L4	0	"5038356".pn. and dbr	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 14:19
L5	1	"5038356".pn. and mirror	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 14:20
L6	1	"5757837".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 14:27
L7	0	"5978401".pn. and (Si or silicon) with (mirror or reflector or Dbr)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:07
L8	888	(driver or circuit) adj2 chip with laser	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:07
L9	143	(driver or circuit) adj2 chip same laser same dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:09
L10	777	integrated adj2 (driver or circuit) same laser same dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:09
L11	245	integrated adj2 (driver or circuit) with dielectric same laser	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:44

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L12	1	integrated adj2 (driver or circuit) with dielectric same laser and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:10
L13	0	"20030002555" and "2218"	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:22
L14	1	"20050094695" and "2218"	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:22
L15	118	integrated adj2 (driver or circuit) same laser adj2 chip	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 16:25
L16	201	absor\$4 adj2 layer with (GaAs or AlGaAs or Gallium adj2 arsenide InGaAs) same (photodetector photodiode detector photo adj (detector diode))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 16:29
L17	11	absor\$4 adj2 layer with (GaAs or AlGaAs or Gallium adj2 arsenide InGaAs) same (photodetector photodiode detector photo adj (detector diode)) and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 16:53
L18	1	"20050094695" and substrate with schottky	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 16:53
S1	7273	(372/43,44,45,46,50).CCLS.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/08/04 19:26
S2	1	S1 and schottkey	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 11:56
S3	50	laser and schottkey	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/04 20:02
S4	20	schottkey adj2 contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 10:51
S5	2	"4,005,469".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/04 20:02

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S25	2	S24 and hybrid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 17:52
S26	104	integrat\$4 same laser same photodiode and hybrid\$4 with circuit	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 17:53
S27	105	(integrat\$4 or monolithic) same laser same photodiode and hybrid\$4 with circuit	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:27
S28	1745	laser same driver same (monolithic or integrat\$)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:29
S29	454	laser same driver same (monolithic or integrat\$) same (photodector or photodiode or detector or photo adj2 (detector diode))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:29
S30	112	laser same driver same (monolithic or integrat\$) same (photodector or photodiode or detector or photo adj2 (detector diode)) and hybrid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:37
S31	72	OEIC and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:38
S32	57	OEIC and laser same driver	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/08/05 18:38
S33	1	"6483862".pn. and schottky	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/03/22 21:26
S34	18	schottky adj2 contact same laser and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/03/22 21:27
S35	2	"4,800,415".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/03/22 21:27

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S36	0	"4,800,415".pn. and schottky	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/03/22 21:33
S37	24	schottky same laser same (photodetector photodiode detector photo adj (detector diode)) and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 11:47
S38	12	(Indium adj2 tin adj2 oxide or ITO) same laser same (photodetector photodiode detector photo adj (detector diode)) and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 11:48
S39	1348	schottky adj2 (contact or diode) with material	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 13:11
S40	7	schottky adj2 (contact or diode or layer) same vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 13:25
S41	702	schottky adj2 contact with diode	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 13:27
S42	122	schottky adj2 contact with (photodiode photodetector detector photo adj diode photo adj detector)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 14:44
S43	319	schottky adj2 detector	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 13:36
S44	7	schottky adj2 detector and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 14:44
S45	0	schottky adj2 sensor and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 14:44
S46	39	schottky with (photodiode photodetector detector photo adj diode photo adj detector) and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 15:12

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S47	1356	vcsl same (photodiode photodetector detector photo adj diode photo adj detector) and (integrated or monolithical\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 15:13
S48	592	vcsl same (photodiode photodetector detector photo adj diode photo adj detector) same (integrated or monolithical\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 17:43
S49	1	"20050094695" and hybrid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 18:23
S50	1	"20040122840"	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 13:40
S51	16	(ITO or indium adj2 tin adj oxide) with semi adj2 insulat\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 19:41
S52	2	"20030002555" and absorb\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 15:21
S53	35	amorphorous adj2 silicon	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 19:18
S54	1128311	"6483862".pn. absorb\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 19:18
S55	1	"6483862".pn. and absorb\$4	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 19:31
S56	75	semi adj2 insulat\$4 with absorb\$4 same (InGaAs or GAs or AlGaAs)	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/23 19:32
S57	1	"5491712".pn. and schottky	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 10:56
S58	1	"5674778".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/24 10:56